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August 2008

# Single-Channel: 6N135, 6N136, HCPL2503, HCPL4502 Dual-Channel: HCPL2530, HCPL2531 High Speed Transistor Optocouplers

# Features

- High speed –1 MBit/s
- Superior CMR 10kV/µs
- Dual-Channel HCPL2530/HCPL2531
- Double working voltage 480V RMS
- CTR guaranteed 0–70°C
- U.L. recognized (File # E90700)

# Applications

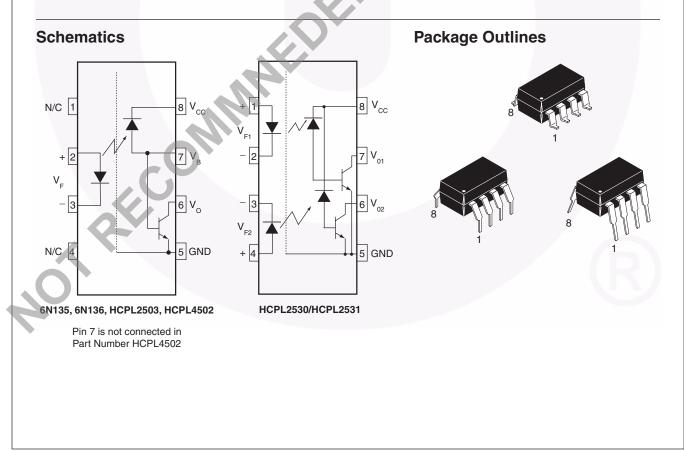
- Line receivers
- Pulse transformer replacement
- Output interface to CMOS-LSTTL-TTL
- Wide bandwidth analog coupling

# Description

The HCPL4502, HCPL2503, 6N135, 6N136, HCPL2530 and HCPL2531 optocouplers consist of an AlGaAs LED optically coupled to a high speed photodetector transistor.

A separate connection for the bias of the photodiode improves the speed by several orders of magnitude over conventional phototransistor optocouplers by reducing the base-collector capacitance of the input transistor.

An internal noise shield provides superior common mode rejection of  $10 kV/\mu s$ . An improved package allows superior insulation permitting a 480V working voltage compared to industry standard of 220V.



# Absolute Maximum Ratings (T<sub>A</sub> = 25°C unless otherwise specified)

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Condition	Value	Units
T <sub>STG</sub>	Storage Temperature		-55 to +125	°C
T <sub>OPR</sub>	Operating Temperature		-55 to +100	°C
T <sub>SOL</sub>	Lead Solder Temperature		260 for 10 sec	°C
EMITTER	1			
I <sub>F</sub> (avg)	DC/Average Forward Input Current Each Channel <sup>(1)</sup>		25	mA
I <sub>F</sub> (pk)	Peak Forward Input Current Each Channel <sup>(2)</sup>	50% duty cycle, 1ms P.W.	50	mA
I <sub>F</sub> (trans)	Peak Transient Input Current Each Channel	≤1µs P.W., 300pps	1.0	A
V <sub>R</sub>	Reverse Input Voltage Each Channel		5	V
P <sub>D</sub>	Input Power Dissipation Each			mW
	Channel	HCPL-2530/253 <sup>(3)</sup>	45	
DETECTO	R			
I <sub>O</sub> (avg)	Average Output Current Each Channel	X	8	mA
I <sub>O</sub> (pk)	Peak Output Current Each Channel		16	mA
V <sub>EBR</sub>	Emitter-Base Reverse Voltage	6N135, 6N136 and HCPL2503 only	5	V
V <sub>CC</sub>	Supply Voltage		-0.5 to 30	V
V <sub>O</sub>	Output Voltage		-0.5 to 20	V
Ι <sub>Β</sub>	Base Current	6N135, 6N136 and HCPL2503 only	5	mA
PD	Output Power Dissipation	6N135, 6N136, HCPL2503, HCPL4502 <sup>(4)</sup>	100	mW
	Each Channel	HCPL2530, HCPL2531	35	mW

#### Notes:

1. Derate linearly above 70°C free-air temperature at a rate of 0.8mA/°C.

2. Derate linearly above 70°C free-air temperature at a rate of 1.6mA/°C.

3. Derate linearly above 70°C free-air temperature at a rate of 0.9 mW/°C.

4. Derate linearly above 70°C free-air temperature at a rate of 2.0 mW/°C.

Symbol	Parameter	Test Conditions	Device	Min.	Тур.*	Max.	Unit
EMITTE	R						
V <sub>F</sub>	Input Forward Voltage	$I_{F} = 16mA, T_{A} = 25^{\circ}C$			1.45	1.7	V
		I <sub>F</sub> = 16mA				1.8	
B <sub>VR</sub>	Input Reverse Breakdown Voltage	I <sub>R</sub> = 10 μΑ		5.0			V
$\Delta V_{F} / \Delta T_{A}$	Temperature Coefficient of Forward Voltage	I <sub>F</sub> = 16mA			-1.6		mV/°C
DETECTO	DR						
I <sub>OH</sub>	Logic High Output Current	$I_F = 0$ mA, $V_O = V_{CC} = 5.5$ V, $T_A = 25^{\circ}$ C	All		0.001	0.5	μA
		$I_F = 0mA$ , $V_O = V_{CC} = 15V$ , $T_A = 25^{\circ}C$	6N135 6N136 HCPL4502 HCPL2503		0.005	1	
		$I_{\rm F} = 0 {\rm mA}, V_{\rm O} = V_{\rm CC} = 15 {\rm V}$	All			50	
I <sub>CCL</sub>	Logic Low Supply Current	$I_F = 16mA, V_O = Open, V_{CC} = 15V$	6N135 6N136 HCPL4502 HCPL2503		120	200	μA
		$I_{F1} = I_{F2} = 16mA,$ V <sub>O</sub> = Open, V <sub>CC</sub> = 15V	HCPL2530 HCPL2531		200	400	
I <sub>CCH</sub>	Logic High Supply Current	$I_F = 0mA, V_O = Open,$ $V_{CC} = 15V, T_A = 25^{\circ}C$	6N135 6N136 HCPL4502 HCPL2503			1	μA
		$I_F = 0mA, V_O = Open,$ $V_{CC} = 15V$	6N135 6N136 HCPL4502 HCPL2503			2	
	Ohi	$I_F = 0mA, V_O = Open,$ $V_{CC} = 15V$	HCPL2530 HCPL2531		0.02	4	

\*All Typicals at  $T_A = 25^{\circ}C$ 

Symbol	Parameter	Test Conditions		Device	Min.	Тур.*	Max.	Unit
COUPLED	0				1			
CTR	Current Transfer Ratio <sup>(5)</sup>	$I_F = 16mA$ , $V_O = 0.4 V$ , $V_{CC} = 4.5V$ , $T_A = 25^{\circ}C$		6N135 HCPL2530	7	18	50	%
				6N136 HCPL4502 HCPL2531	19	27	50	%
				HCPL2503	12	27		%
		I <sub>F</sub> = 16mA,	$V_{OL} = 0.4V$	6N135	5 21		%	
		$V_{CC} = 4.5V$	$V_{OL} = 0.5V$	HCPL2530				
			$V_{OL} = 0.4 V$	6N136 HCPL4502	15	30		%
			$V_{OL} = 0.5V$	HCPL2531				
			$V_{OL} = 0.4V$	HCPL2503	9	30		%
V <sub>OL</sub>	Logic LOW Output	V Output $I_F = 16mA$ , $I_O = 1.1mA$		6N135		0.18	0.4	V
	Voltage	$V_{CC} = 4.5V, T_{A} = 25$	°C	HCPL2530		0.18	0.5	
		$I_F = 16mA, I_O = 3mA,$ $V_{CC} = 4.5V, T_A = 25^{\circ}C$		6N136 HCPL2503		0.25	0.4	
	I <sub>F</sub> = 16mA, I <sub>O</sub> = 0.8n V <sub>CC</sub> = 4.5V			HCPL2531		0.25	0.5	5
			BmA,	6N135 HCPL2530			0.5	
		$I_F = 16mA, I_O = 2.4$ $V_{CC} = 4.5V$	·mA,	HCPL4502 HCPL2531			0.5	

\*All Typicals at  $T_A = 25^{\circ}C$ 

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Current Transfer Ratio is defined as a ratio of output collector current, I<sub>O</sub>, to the forward LED input current, I<sub>F</sub>, times 100%.

Single-Channel: 6N135, 6N136 , HCPL2503, HCPL4502 Dual-Channel: HCPL2530, HCP
135, 6N136 ,
, HCPL2503,
HCPL4502
Dual-Chann
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30, HCPL253
1 — High Sp
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or Optocoupler
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### **Switching Characteristics** (V<sub>CC</sub> = 5V)

Symbol	Parameter	Test Conditions	Device	Min.	Тур.*	Max.	Unit
T <sub>PHL</sub>	Propagation Delay Time to Logic LOW	$\begin{split} T_{A} &= 25^{\circ}C, \ R_{L} = 4.1 k\Omega, \\ I_{F} &= 16 m A^{(6)} \ (\text{Fig. 7}) \end{split}$	6N135 HCPL2530		0.45	1.5	μs
		$R_L = 1.9k\Omega$ , $I_F = 16mA$ , $T_A = 25°C^{(7)}$ (Fig. 7)	6N136 HCPL4502 HCPL2503 HCPL2531		0.45	0.8	μs
		$R_L = 4.1 k\Omega$ , $I_F = 16 mA^{(6)}$ (Fig. 7)	6N135 HCPL2530			2.0	μs
		$R_L = 1.9 k\Omega$ , $I_F = 16 mA^{(7)}$ (Fig. 7)	6N136 HCPL4502 HCPL2503 HCPL2531		O	1.0	μs
T <sub>PLH</sub>	Propagation Delay Time to Logic HIGH	$\begin{split} T_{A} &= 25^{\circ}C,  (R_{L} = 4.1 k \Omega, \\ I_{F} &= 16 m A^{(6)}  (Fig.  7) \end{split}$	6N135 HCPL2530		0.5	1.5	μs
		$R_L = 1.9k\Omega$ , $I_F = 16mA^{(7)}$ (Fig. 7) $T_A = 25°C$	6N136 HCPL4502 HCPL2503 HCPL2531		0.3	0.8	μs
		$R_L = 4.1 k\Omega$ , $I_F = 16 mA^{(6)}$ (Fig. 7)	6N135 HCPL2530			2.0	μs
		$R_{L} = 1.9k\Omega$ , $I_{F} = 16mA^{(7)}$ (Fig. 7)	6N136 HCPL4502 HCPL2503 HCPL2531			1.0	μs
ICM <sub>H</sub> I	Common Mode Transient	$    I_F = 0mA, V_{CM} = 10V_{P-P}, \\ R_L = 4.1 k\Omega, T_A = 25^\circ C^{(8)} \text{ (Fig. 8)} $	6N135 HCPL2530		10,000		V/µs
	Immunity at Logic High	$    I_F = 0mA, V_{CM} = 10V_{P-P}, \\ R_L = 1.9k\Omega, T_A = 25^{\circ}C^{(8)} \text{ (Fig. 8)} $	6N136 HCPL4502 HCPL2503 HCPL2531		10,000		V/µs
ICM <sub>L</sub> I	Common Mode Transient	$\begin{split} I_{\text{F}} &= 16\text{mA},  V_{\text{CM}} = 10  V_{\text{P-P}}, \\ R_{\text{L}} &= 4.1 \text{k} \Omega,  T_{\text{A}} = 25^{\circ}\text{C}^{(8)}  (\text{Fig. 8}) \end{split}$	6N135 HCPL2530		10,000		V/µs
	Immunity at Logic Low	$I_{F} = 16 \text{mA}, V_{CM} = 10 V_{P-P},$ $R_{L} = 1.9 \text{k} \Omega^{(8)} \text{ (Fig. 8)}$	6N136 HCPL4502 HCPL2503 HCPL2531		10,000		V/µs

# \*\* All Typicals at $T_A = 25^{\circ}C$

Notes:

6. The 4.1k\Omega load represents 1 LSTTL unit load of 0.36mA and 6.1kΩ pull-up resistor.

7. The 1.9k\Omega load represents 1 TTL unit load of 1.6mA and 5.6k\Omega pull-up resistor.

8. Common mode transient immunity in logic high level is the maximum tolerable (positive)  $dV_{cm}/dt$  on the leading edge of the common mode pulse signal  $V_{CM}$ , to assure that the output will remain in a logic high state (i.e.,  $V_O > 2.0V$ ). Common mode transient immunity in logic low level is the maximum tolerable (negative)  $dV_{cm}/dt$  on the trailing edge of the common mode pulse signal,  $V_{CM}$ , to assure that the output will remain in a logic low state (i.e.,  $V_O > 2.0V$ ).

<b>Electrical Characteristics</b>	(Continued) ( $T_A = 0$ to 70°C unless otherwise specified)
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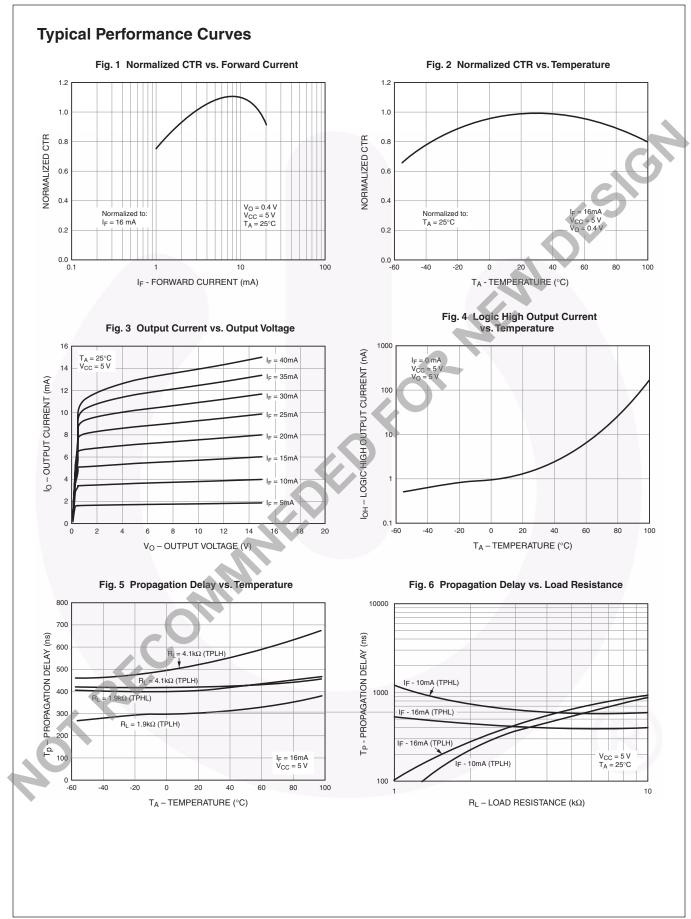
Symbol	Characteristics	Test Conditions	Min	Typ**	Max	Unit
I <sub>I-O</sub>	Input-Output Insulation Leakage Current	Relative humidity = 45%, $T_A = 25^{\circ}C$ , t = 5s, $V_{I-O} = 3000 \text{ VDC}^{(9)}$			1.0	μA
V <sub>ISO</sub>	Withstand Insulation Test Voltage	$ \begin{array}{l} RH \leq 50\%,  T_{A} = 25^{\circ}C,  I_{I-O} \leq 2\mu A, \\ t = 1  \mbox{ min.}^{(9)} \end{array} $	2500			V <sub>RMS</sub>
R <sub>I-O</sub>	Resistance (Input to Output)	$V_{I-O} = 500 VDC^{(9)}$		10 <sup>12</sup>		Ω
C <sub>I-O</sub>	Capacitance (Input to Output)	$f = 1 MHz^{(9)}$		0.6		pF
HFE	DC Current Gain	$I_{O} = 3mA, V_{O} = 5V^{(9)}$		150		
I <sub>I-I</sub>	Input-Input Insulation Leakage Current	$\begin{array}{l} RH \leq 45\%,  V_{I\text{-}I} = 500 VDC^{(10)} \\ t = 5 \; s,  (HCPL2530/2531 \; only) \end{array}$		0.005		μA
R <sub>I-I</sub>	Input-Input Resistance	V <sub>I-I</sub> = 500 VDC <sup>(10)</sup> (HCPL2530/2531 only)		1011		Ω
C <sub>I-I</sub>	Input-Input Capacitance	f = 1MHz) <sup>(10)</sup> (HCPL2530/2531 only)	S	0.03		pF

**Isolation Characteristics** ( $T_A = 0$  to 70°C Unless otherwise specified)

#### Notes:

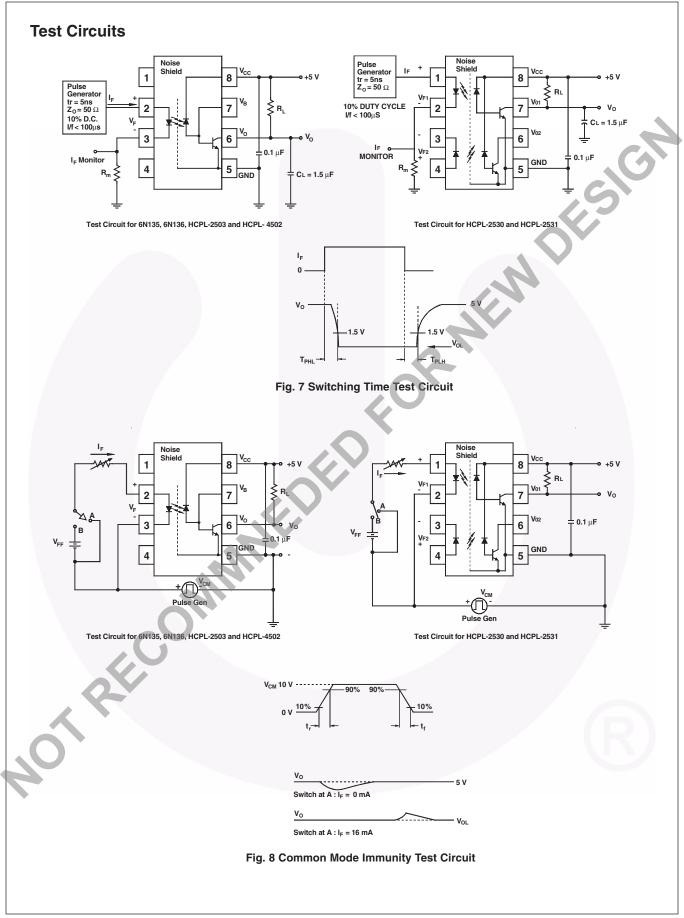
9. Device is considered a two terminal device: Pins 1, 2, 3 and 4 are shorted together and Pins 5, 6, 7 and 8 are shorted together.

10. Measured between pins 1 and 2 shorted together, and pins 3 and 4 shorted together.



Single-Channel: 6N135, 6N136, HCPL2503, HCPL4502 Dual-Channel: HCPL2530, HCPL2531 — High Speed Transistor Optocouplers

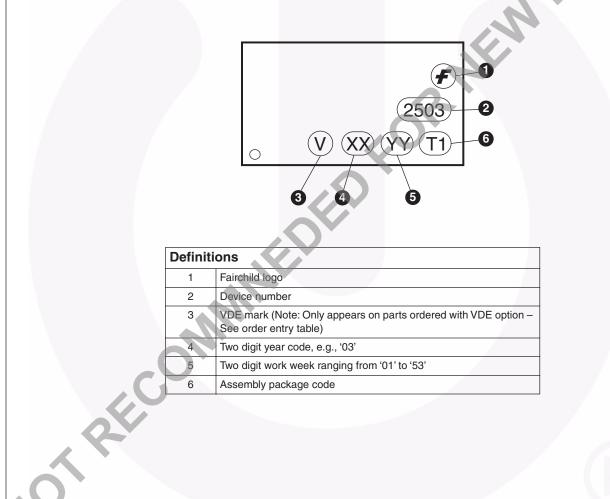
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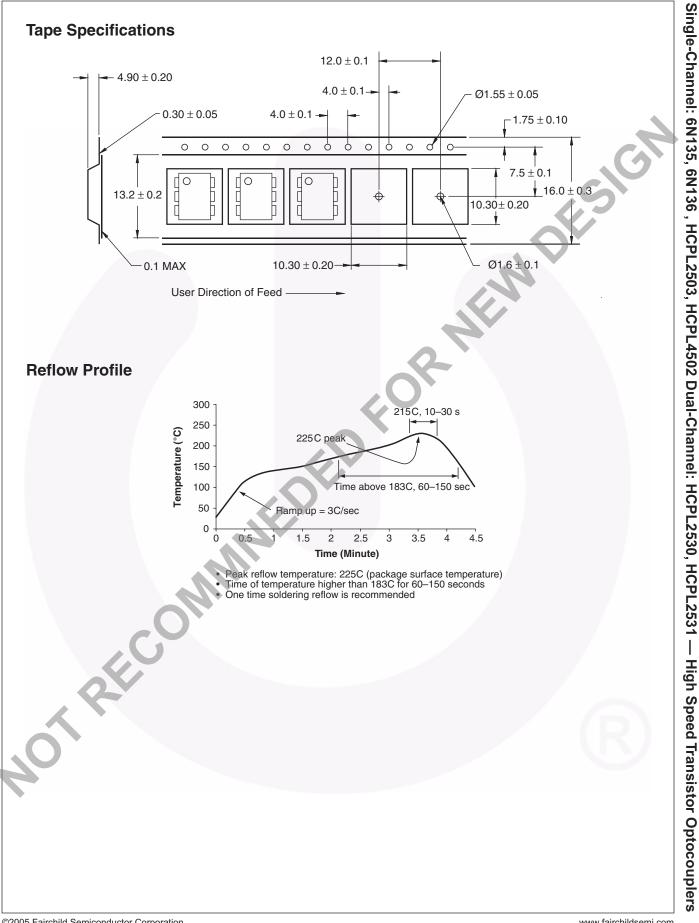


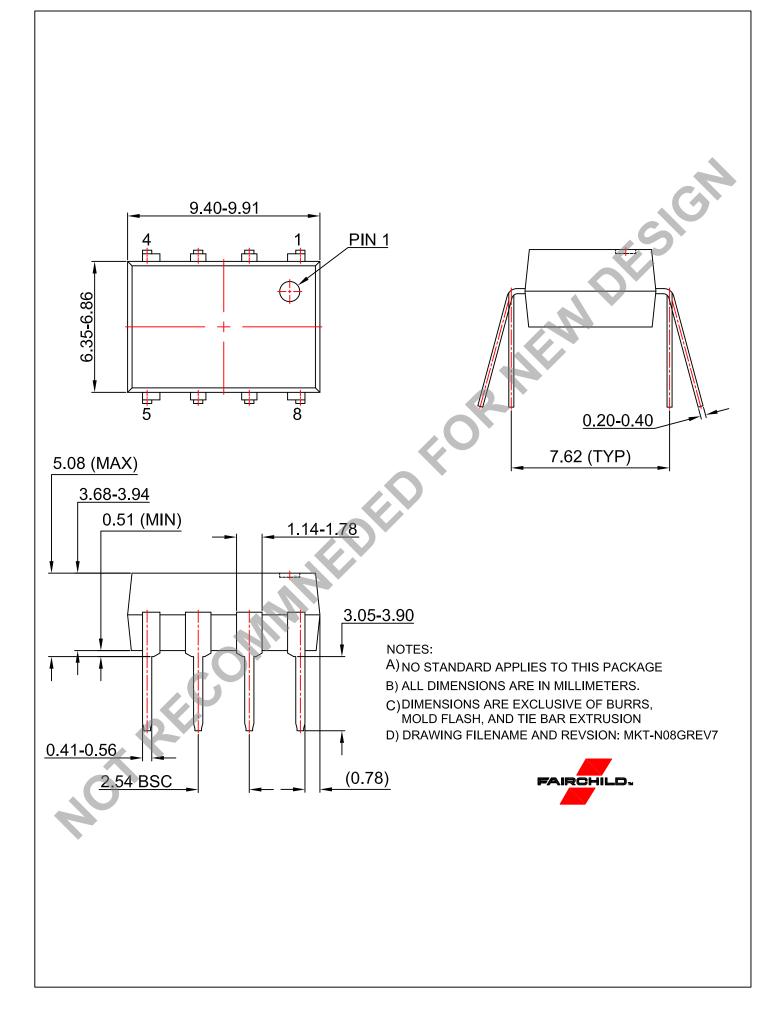
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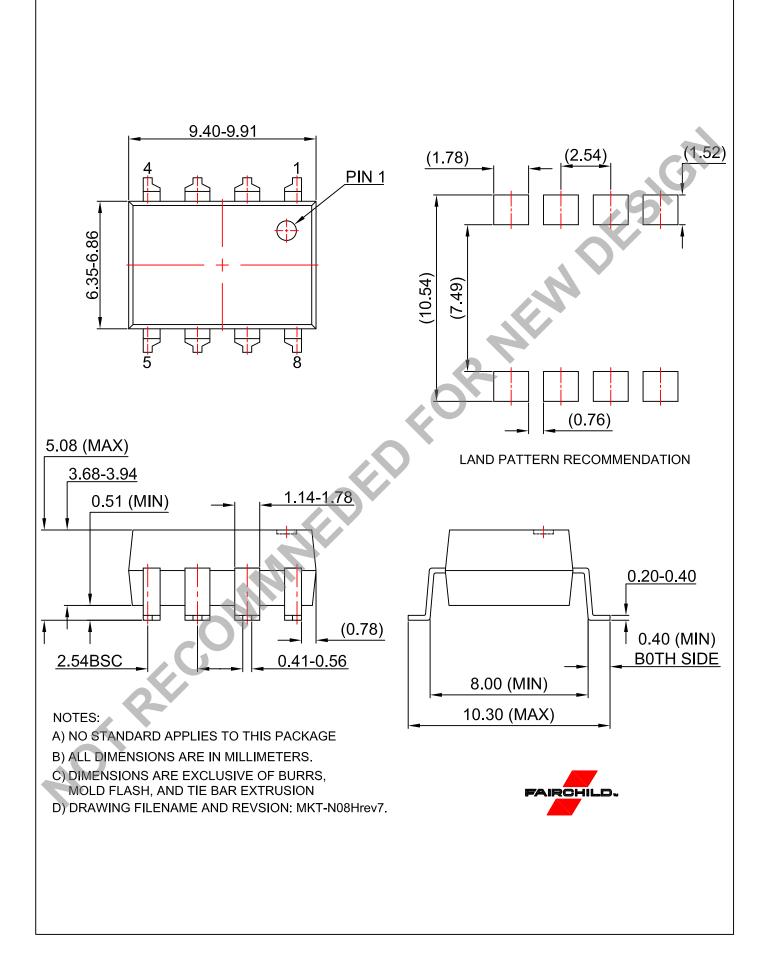
dering Information						
Option	Example Part Number	Description				
S	6N135S	Surface Mount Lead Bend				
SD	6N135SD	Surface Mount; Tape and reel				
W	6N135W	0.4" Lead Spacing				
V	6N135V	VDE0884				
WV	6N135WV	VDE0884; 0.4" lead spacing				
SV	6N135SV	VDE0884; surface mount				
SDV	VDE0884; surface mount; tape and reel					

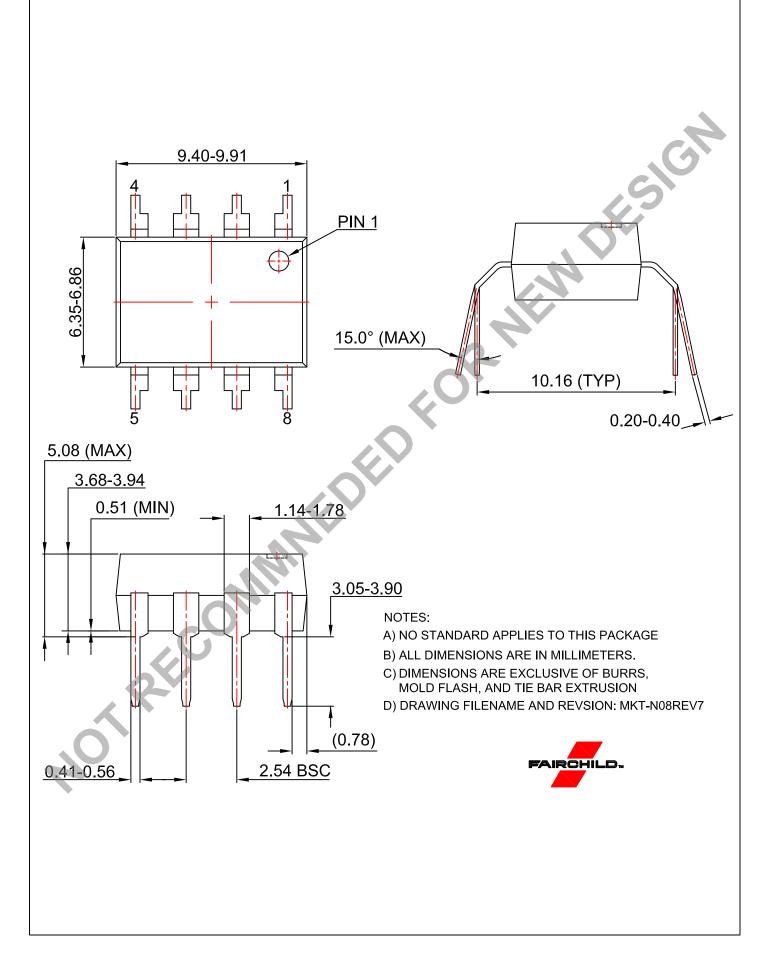
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